

Zenith-100

RTP - SYSTEM

High temperature RTP system

RTP and RTCVD processes

High vacuum

Annealing processes up to 2000°C



Specifications

The Zenith-100 high temperature rapid thermal processor can process samples up to 4-inch diameter at temperature up to 2000°C.

The system has a stainless steel water-cooled chamber. The cold wall chamber technology provides significant advantages: low memory effect, higher cooling rates.

The high temperature tungsten heaters provide enhanced temperature uniformity.

The pyrometer associated with the fast digital PID controller assure accurate and repeatable thermal control across the temperature range.

The design process chamber provides easy loading and unloading of the substrates and the installation of the thermocouple for calibration.

Applications

Silicon Carbide implant annealing
Graphene by SiC sublimation
RTCVD of graphene
High temperature annealing

Full PC control, up to 100 steps per recipe

Control Human interface designed in respect of SEMI E95-0200

Full data logging and process historicals

Optional features

Graphite and silicon carbide coated susceptors Rough vacuum pump Automatic pressure control with throttle valve

Customer support

Outstanding customer support for hardware, software and process Efficient remote support using software diagnostic capabilities High expertise in RTP processes of our process engineers Capability to support customer for process optimization

Physical specifications

Facilities

Voltage: 3x400V+N+Gr / 3x220V+Gr

Power: 38 kW

Water : 2 to 4 bars, pressure drop 1 bar, 15 I/mn

Compressed air: 6 bars (valve actuation)

Process gas fittings: VCR ¼

 Dimensions and weight
 Width B00 mm B00 m







139 rue des Walkyries 34000 Montpellier - FRANCE

Tel: +33 467 20 23 63 Fax: +33 467 20 26 89 Email: sales@annealsys.com

www.annealsys.com